

Absolute maximum ratings (Ta=25°C)

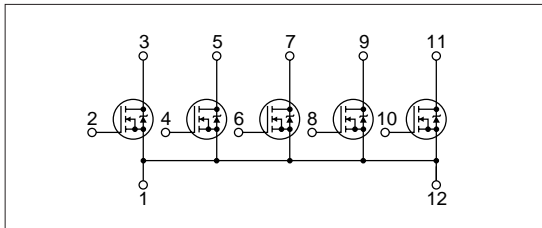
Symbol	Ratings	Unit
V _{DSS}	200	V
V _{GSS}	±20	V
I _D	±7	A
I _{D(pulse)}	±15 (PW≤1ms, Du≤1%)	A
EAS*	55	mJ
P _T	5 (Ta=25°C, with all circuits operating, without heatsink)	W
	35 (Tc=25°C, with all circuits operating, with infinite heatsink)	W
θ _{j-a}	25 (Junction-Air, Ta=25°C, with all circuits operating)	°C/W
θ _{j-c}	3.57 (Junction-Case, Tc=25°C, with all circuits operating)	°C/W
V _{ISO}	1000 (Between fin and lead pin, AC)	V _{rms}
T _{ch}	150	°C
T _{stg}	-40 to +150	°C

* : V_{DD}=25V, L=2.0mH, I_D=7A, unclamped, R_G=50Ω, see Fig. E on page 15.

Electrical characteristics (Ta=25°C)

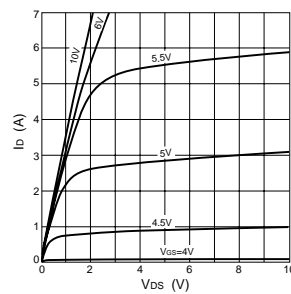
Symbol	Specification			Unit	Conditions
	min	typ	max		
V _{(BR)DSS}	200			V	I _D =100μA, V _{GS} =0V
I _{GSS}			±100	nA	V _{GS} =±20V
I _{DSS}			100	μA	V _{DS} =200V, V _{GS} =0V
V _{TH}	2.0		4.0	V	V _{DS} =10V, I _D =1mA
Re _(yfs)	2.5	5.0		S	V _{DS} =10V, I _D =3.5A
R _{DS(ON)}		270	350	mΩ	V _{GS} =10V, I _D =3.5A
C _{ISS}		450		pF	V _{DS} =10V, f=1.0MHz, V _{GS} =0V
C _{OSS}		280		pF	
C _{RSS}		120		pF	
td(on)		20		ns	I _D =3.5A, V _D ≐100V, R _L =28.6Ω, V _{GS} =10V, see Fig. 3 on page 16.
tr		30		ns	
td(off)		55		ns	
tf		75		ns	
V _{SD}		1.0	1.5	V	
trr		450		ns	I _{SD} =±100mA

Equivalent circuit diagram

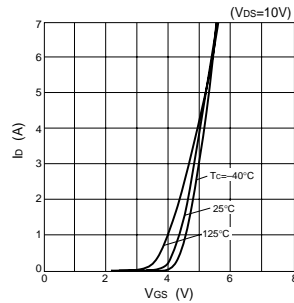


Characteristic curves

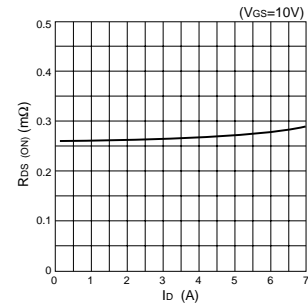
I_D-V_{DS} Characteristics (Typical)



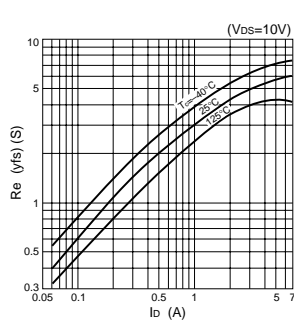
I_D-V_{GS} Characteristics (Typical)



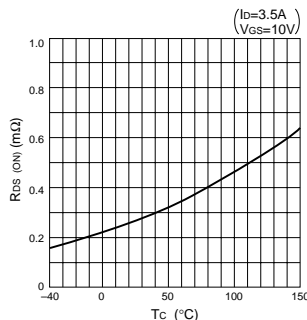
R_{DS(ON)}-I_D Characteristics (Typical)



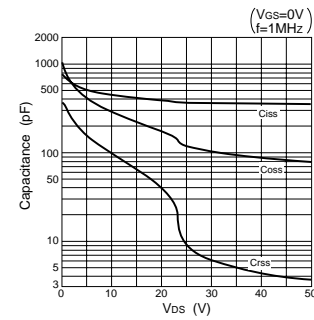
Re_(yfs)-I_D Characteristics (Typical)



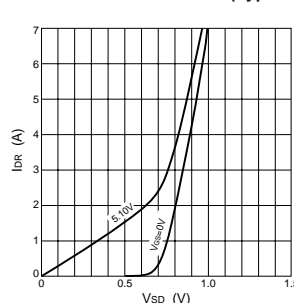
R_{DS(ON)}-T_C Characteristics (Typical)



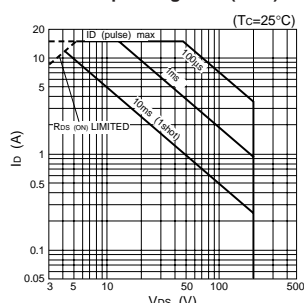
Capacitance-V_{DS} Characteristics (Typical)



I_{DR}-V_{SD} Characteristics (Typical)



Safe Operating Area (SOA)



P_T-T_a Characteristics

